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<u>Diodes Incorporated</u> <u>DMN6140L-7</u>

For any questions, you can email us directly: sales@integrated-circuit.com



Datasheet of DMN6140L-7 - MOSFET N-CH 60V 1.6A SOT-23

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com





DMN6140L

60V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on) max}	I _D T _A = +25°C
60V	140m Ω @ V _{GS} = 10V	2.3A
	170mΩ @ $V_{GS} = 4.5V$	2.1A

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Power Management Functions
- Analog Switch

Features and Benefits

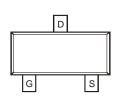
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

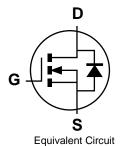
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0072 grams (Approximate)







Pin Configuration



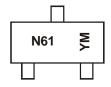
Part Number	Case	Packaging
DMN6140L-7	SOT23	3,000/Tape & Reel
DMN6140L-13	SOT23	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Ordering Information (Note 4)



N61 = Marking Code YM = Date Code Marking Y = Year (ex: Y = 2011) M = Month (ex: 9 = September)

Date Code Key

Year	201	1	2012		2013	20	14	2015		2016	2	2017
Code	Υ		Z		Α		3	С		D		Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Drain-Source Voltage	V _{DSS}	60	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Out Dui - Our (Alan - 5) V 40 V	Steady State	$T_A = +25$ °C $T_A = +70$ °C	I _D	1.6 1.2	А
Continuous Drain Current (Note 5) V _{GS} = 10V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	2.0 1.6	А
Continuous Davis Comment (Note C) V 40V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	2.3 1.8	А
Continuous Drain Current (Note 6) V _{GS} = 10V	t<10s	$T_A = +25$ °C $T_A = +70$ °C	I _D	2.9 2.3	А
Maximum Continuous Body Diode Forward Curren	Is	1.5	А		
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	10	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P_{D}	0.7	W
Total Fower Dissipation (Note 5)	$T_A = +70^{\circ}C$	FD	0.4	VV
Thermal Resistance, Junction to Ambient (Note 5)	Steady State		183	°C/W
Thermal Resistance, Junction to Ambient (Note 3)	t<10s	$R_{\theta JA}$	115	C/VV
Total Power Dissipation (Note 6)	$T_A = +25$ °C	D-	1.3	W
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	P _D	0.8	VV
Thermal Resistance, Junction to Ambient (Note 6)	Steady State		94	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	61	°C/W
Thermal Resistance, Junction to Case		$R_{ heta JC}$	39	
Operating and Storage Temperature Range		$T_{J_{I}}T_{STG}$	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

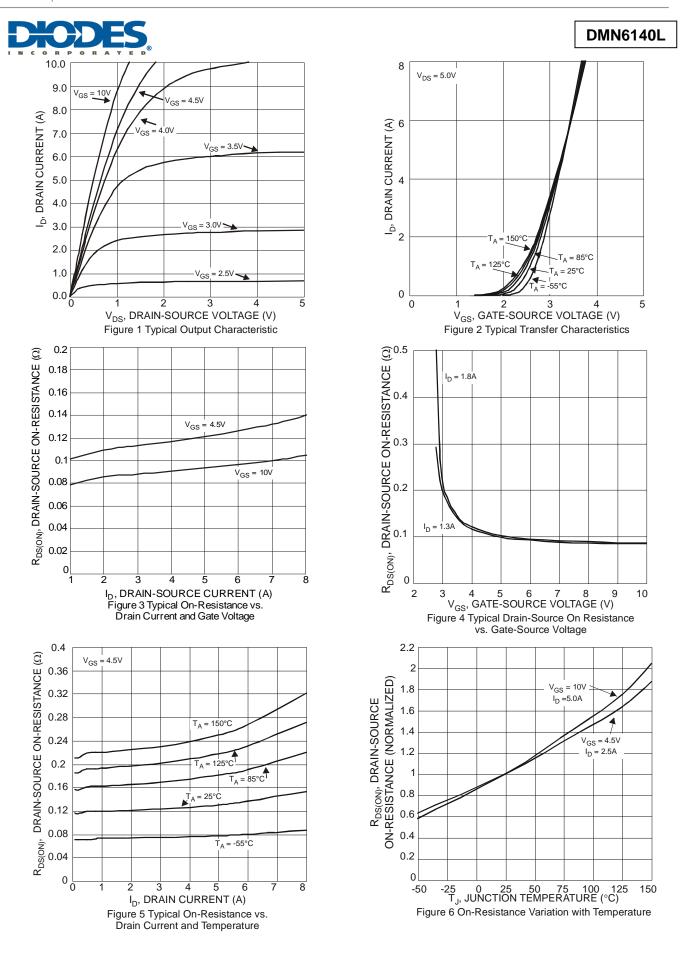
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)				•	•	•	
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_		1	μΑ	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	1	_	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance	D		92	140	mΩ	$V_{GS} = 10V, I_D = 1.8A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	115	170	11122	$V_{GS} = 4.5V, I_D = 1.3A$	
Forward Transfer Admittance	Y _{fs}	_	2.2	_	S	$V_{DS} = 15V, I_{D} = 1.8A$	
Diode Forward Voltage	V_{SD}	_	0.75	1.0	V	$V_{GS} = 0V, I_{S} = 0.45A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	_	315	_		V _{DS} = 40V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	Coss	_	18	_	pF		
Reverse Transfer Capacitance	Crss	_	16	_			
Gate Resistnace	R_g	_	0.65	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 10V)	Q_g	_	8.6	_			
Total Gate Charge (V _{GS} = 5V)	Q_g	_	4.1	_	nC	V 20V I- 4.0A	
Gate-Source Charge	Q_{gs}	_	1.0	_	IIC	$V_{DS} = 30V, I_D = 1.8A$	
Gate-Drain Charge	Q_{gd}	_	1.7	_			
Turn-On Delay Time	t _{D(on)}	_	2.6	_			
Turn-On Rise Time	t _r —		3.6	_	ì	$V_{DS} = 30V, V_{GS} = 10V,$	
Turn-Off Delay Time	t _{D(off)}	_	16.3	_	ns	$R_G = 6.0\Omega, I_D = 1.8A$	
Turn-Off Fall Time	t _f	_	2.7	_			
Reverse Recovery Time	t _{rr}	_	16.8	_	ns	1 4 0 4 3 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4	
Reverse Recovery Charge	Q _{rr}	_	9.0	_	nC	I _F = 1.8A, di/dt =100A/μs	

Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1in. square copper plate.
- $\label{eq:continuous} 7 \ . \\ \text{Short duration pulse test used to minimize self-heating effect.}$
- 8. Guaranteed by design. Not subject to production testing.

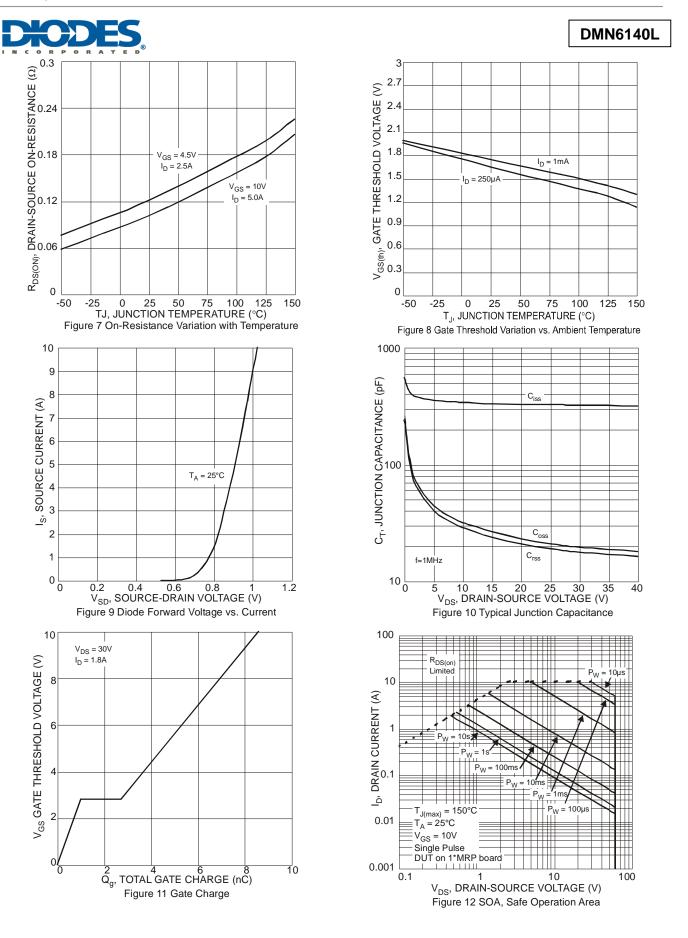
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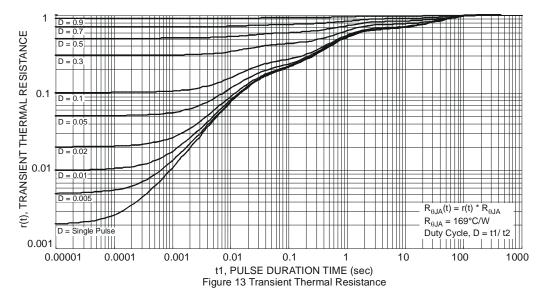


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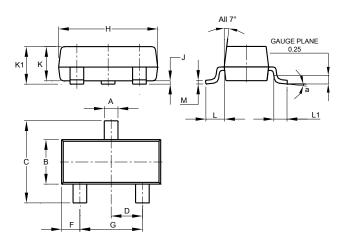


DMN6140L



Package Outline Dimensions

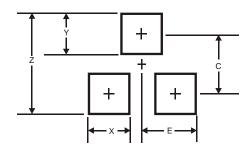
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
C	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
M	0.085	0.150	0.110				
α	8°						
All	All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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